NSN 5962-01-160-7725

Memory Microcircuit - Page 1 of 1



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Body Length:

Between 1.380 inches and 1.430 inches

Body Width:

Between 0.580 inches and 0.610 inches

Body Height:

Between 0.080 inches and 0.120 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Radar system an/fps-117

Features Provided:

Programmable

Inclosure Material:

inclosure mate

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

17 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

80.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Pal

Test Data Document:

03538-7849722 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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